# NCE N-Channel Super Trench II Power MOSFET

## Description

The series of devices uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and $Q_g$. This device is ideal for high-frequency switching and synchronous rectification.

## Application

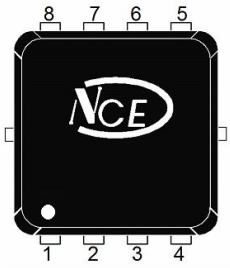
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

## General Features

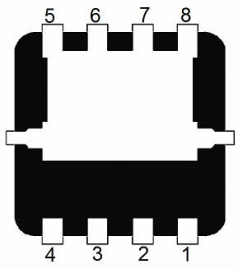
- $V_{DS}$ =30V,$I_D$ =70A
  $R_{DS(ON)}$=1.75mΩ (typical) @ $V_{GS}$=10V
  $R_{DS(ON)}$=3.0mΩ (typical) @ $V_{GS}$=4.5V
- Excellent gate charge x $R_{DS(on)}$ product(FOM)
- Very low on-resistance $R_{DS(on)}$
- 150 °C operating temperature
- Pb-free lead plating

***100% UIS TESTED!***
***100% ΔVds TESTED!***

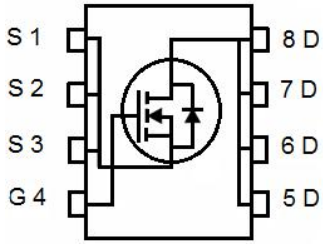
**DFN 3.3X3.3**




Top View




Bottom View




Schematic Diagram

## Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|---|---|---|---|---|---|
| NCEP020N30QU | NCEP020N30QU | DFN3.3X3.3-8L | - | - | - |

## Absolute Maximum Ratings ($T_C$=25℃unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|---|---|---|
| Drain-Source Voltage | $V_{DS}$ | 30 | V |
| Gate-Source Voltage | $V_{GS}$ | ±20 | V |
| Drain Current-Continuous | $I_D$ | 70 | A |
| Drain Current-Continuous($T_C$=100℃) | $I_D$ (100℃) | 55 | A |
| Pulsed Drain Current | $I_{DM}$ | 280 | A |
| Maximum Power Dissipation | $P_D$ | 55 | W |
| Derating factor | | 0.44 | W/℃ |
| Single pulse avalanche energy (Note 5) | $E_{AS}$ | 352 | mJ |
| Operating Junction and Storage Temperature Range | $T_J$,$T_{STG}$ | -55 To 150 | ℃ |

## Thermal Characteristic

| | | | |
|---|---|---|---|
| Thermal Resistance,Junction-to-Case (Note 2) | $R_{\theta JC}$ | 2.3 | ℃/W |

## Electrical Characteristics ($T_C$=25℃unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| **Off Characteristics** | | | | | | |
| Drain-Source Breakdown Voltage | $BV_{DSS}$ | $V_{GS}$=0V $I_D$=250μA | 30 | | - | V |
| Zero Gate Voltage Drain Current | $I_{DSS}$ | $V_{DS}$=30V,$V_{GS}$=0V | - | - | 1 | μA |
| Gate-Body Leakage Current | $I_{GSS}$ | $V_{GS}$=±20V,$V_{DS}$=0V | - | - | ±100 | nA |
| **On Characteristics** (Note 3) | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}$=$V_{GS}$,$I_D$=250μA | 1.0 | 1.6 | 2.0 | V |
| Drain-Source On-State Resistance | $R_{DS(ON)}$ | $V_{GS}$=10V, $I_D$=35A | - | 1.75 | 2.0 | mΩ |
| | | $V_{GS}$=4.5V, $I_D$=35A | - | 3.0 | 4.0 | mΩ |
| Forward Transconductance | $g_{FS}$ | $V_{DS}$=5V,$I_D$=35A | | 65 | - | S |
| **Dynamic Characteristics** (Note4) | | | | | | |
| Input Capacitance | $C_{lss}$ | $V_{DS}$=15V,$V_{GS}$=0V, F=1.0MHz | - | 2400 | - | PF |
| Output Capacitance | $C_{oss}$ | | - | 1700 | - | PF |
| Reverse Transfer Capacitance | $C_{rss}$ | | - | 120 | - | PF |
| **Switching Characteristics** (Note 4) | | | | | | |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD}$=15V,$I_D$=35A $V_{GS}$=10V,$R_G$=1.6Ω | - | 5.0 | - | nS |
| Turn-on Rise Time | $t_r$ | | - | 7.0 | - | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 27.0 | - | nS |
| Turn-Off Fall Time | $t_f$ | | - | 5.0 | - | nS |
| Total Gate Charge | $Q_g$ | $V_{DS}$=15V,$I_D$=35A, $V_{GS}$=10V | - | 40.5 | - | nC |
| Gate-Source Charge | $Q_{gs}$ | | - | 6.5 | | nC |
| Gate-Drain Charge | $Q_{gd}$ | | - | 7 | | nC |
| **Drain-Source Diode Characteristics** | | | | | | |
| Diode Forward Voltage (Note 3) | $V_{SD}$ | $V_{GS}$=0V,$I_S$=35A | - | | 1.2 | V |
| Diode Forward Current (Note 2) | $I_S$ | | - | - | 70 | A |
| Reverse Recovery Time | $t_{rr}$ | $T_J$ = 25°C, $I_F$ = $I_S$ di/dt = 100A/μs (Note3) | - | 14 | - | nS |
| Reverse Recovery Charge | Qrr | | - | 21 | - | nC |

## Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production
5. EAS condition : Tj=25℃,$V_{DD}$=20V,$V_G$=10V,L=0.5mH,Rg=25Ω

## Typical Electrical and Thermal Characteristics

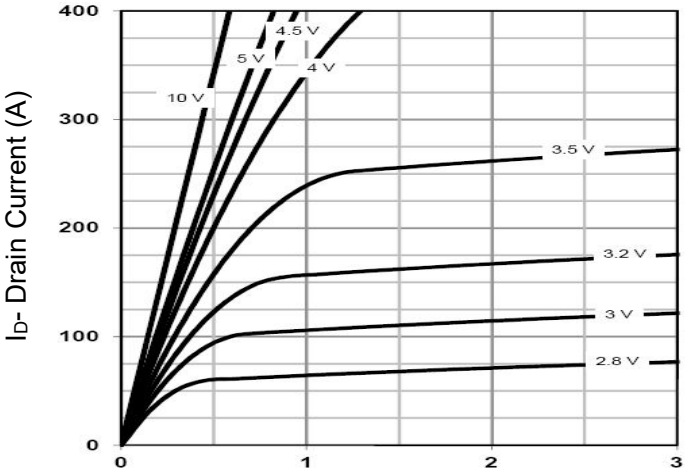



**Figure 1 Output Characteristics**

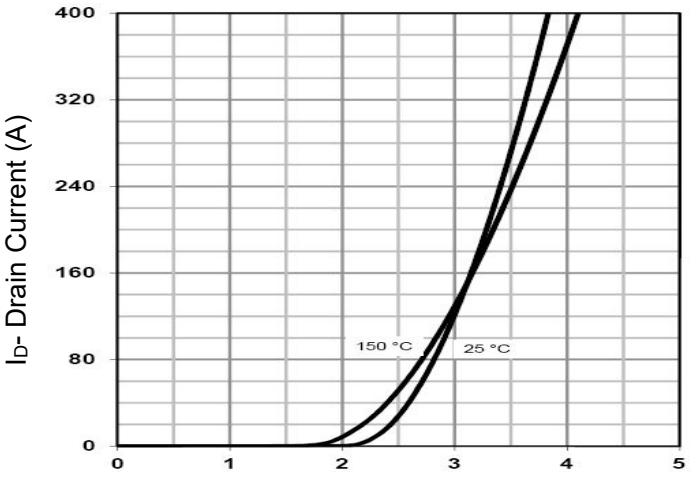



**Figure 2 Transfer Characteristics**

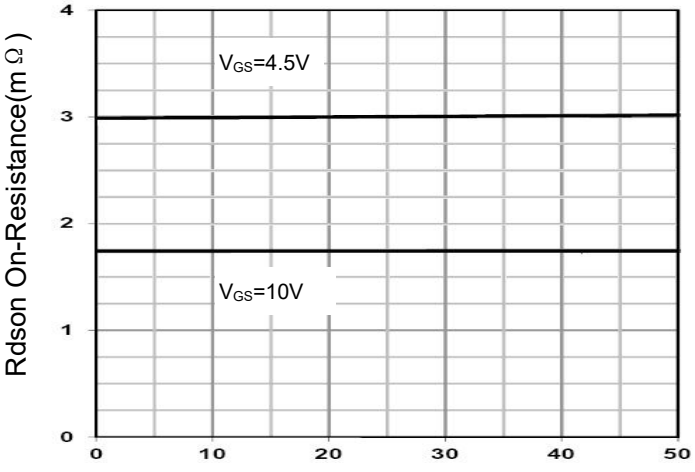



**Figure 3 Rdson- Drain Current**

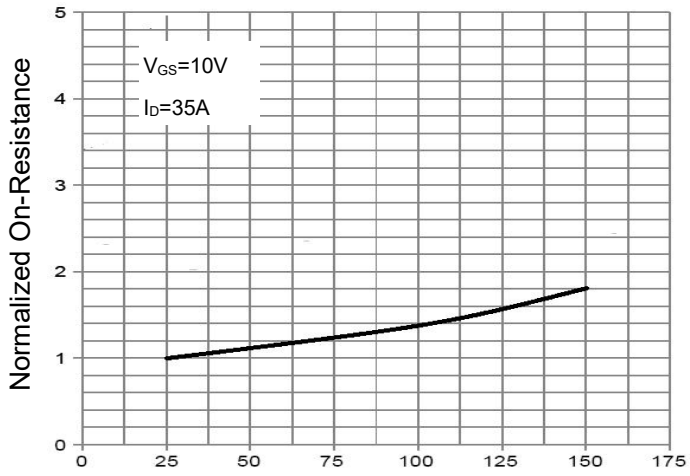



**Figure 4 Rdson-Junction Temperature**

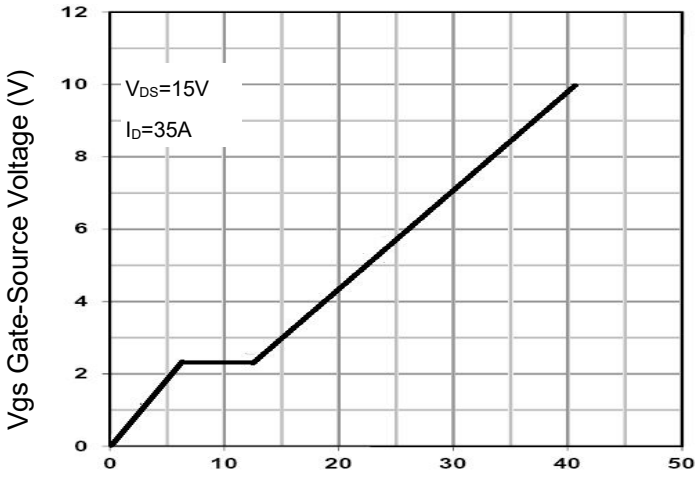



**Figure 5 Gate Charge**

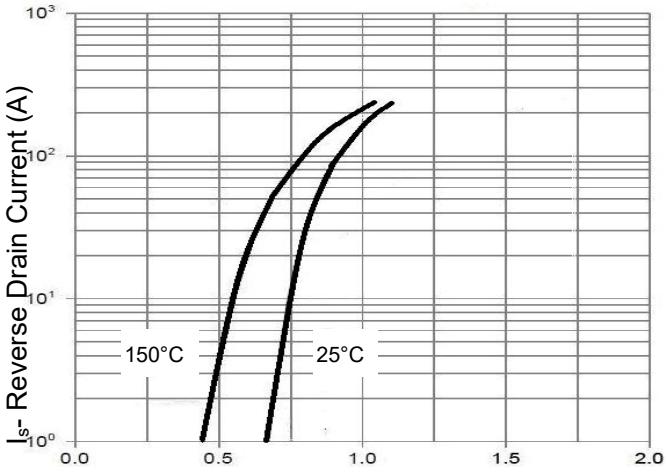



**Figure 6 Source- Drain Diode Forward**

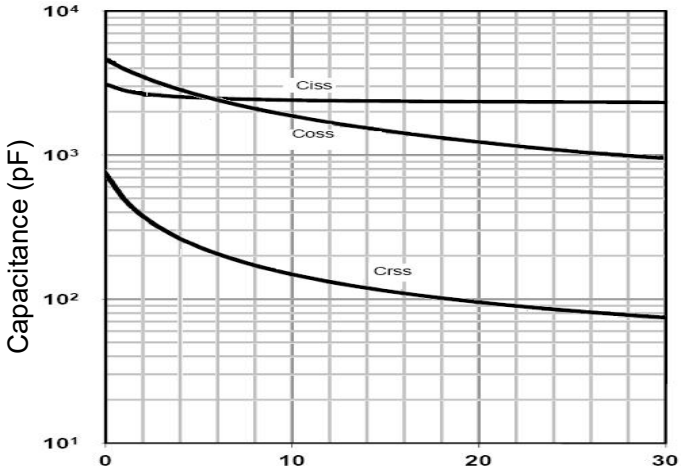



**Figure 7 Capacitance vs Vds**

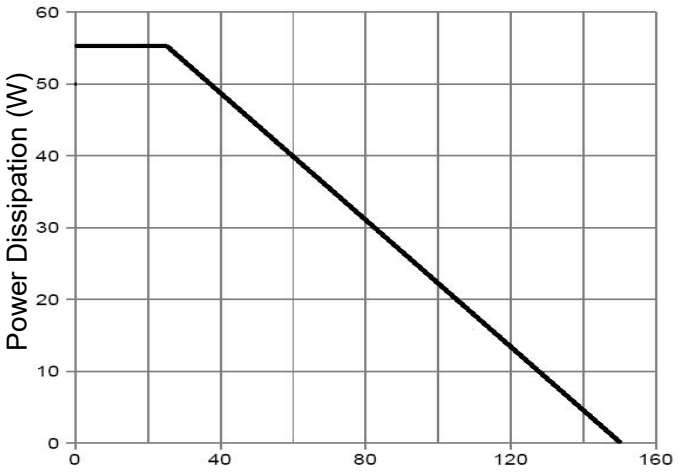



**Figure 9 Power De-rating**

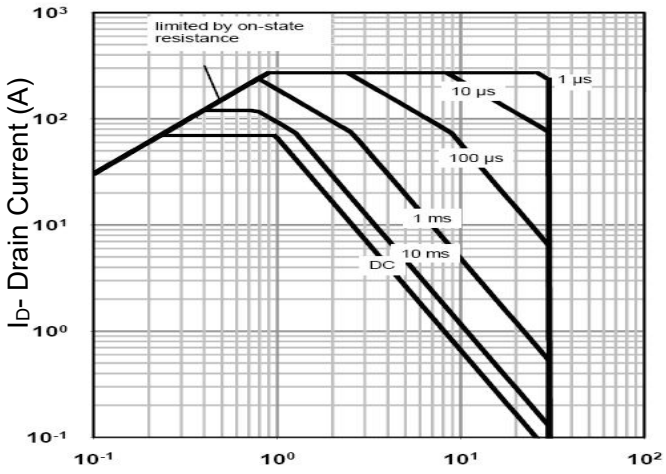



**Figure 8 Safe Operation Area**

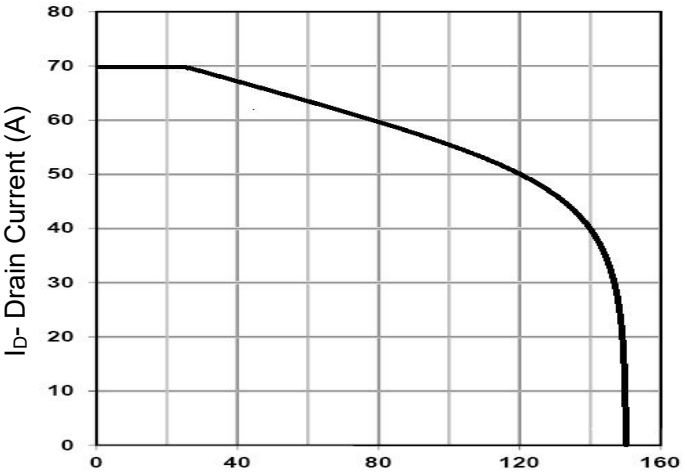



**Figure 10 Current De-rating**

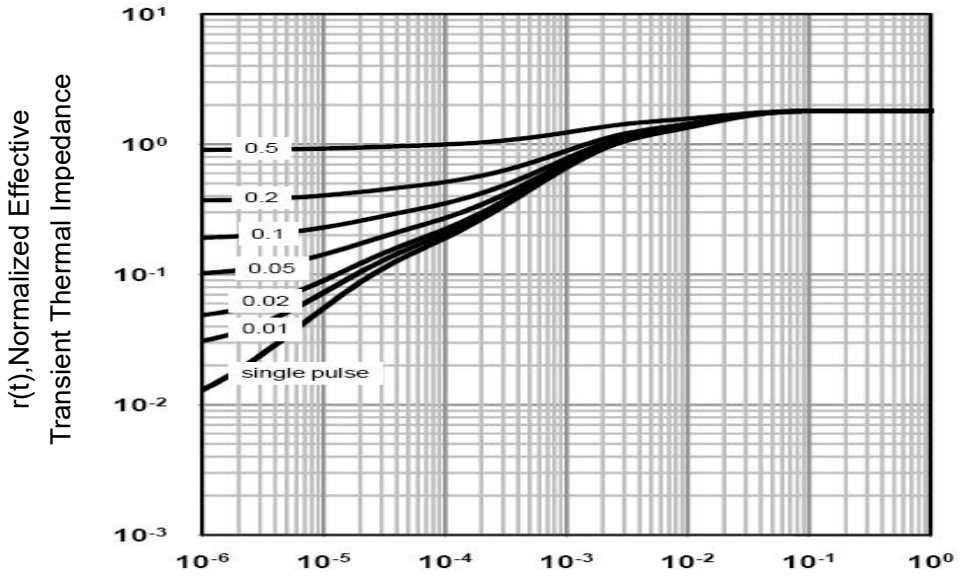
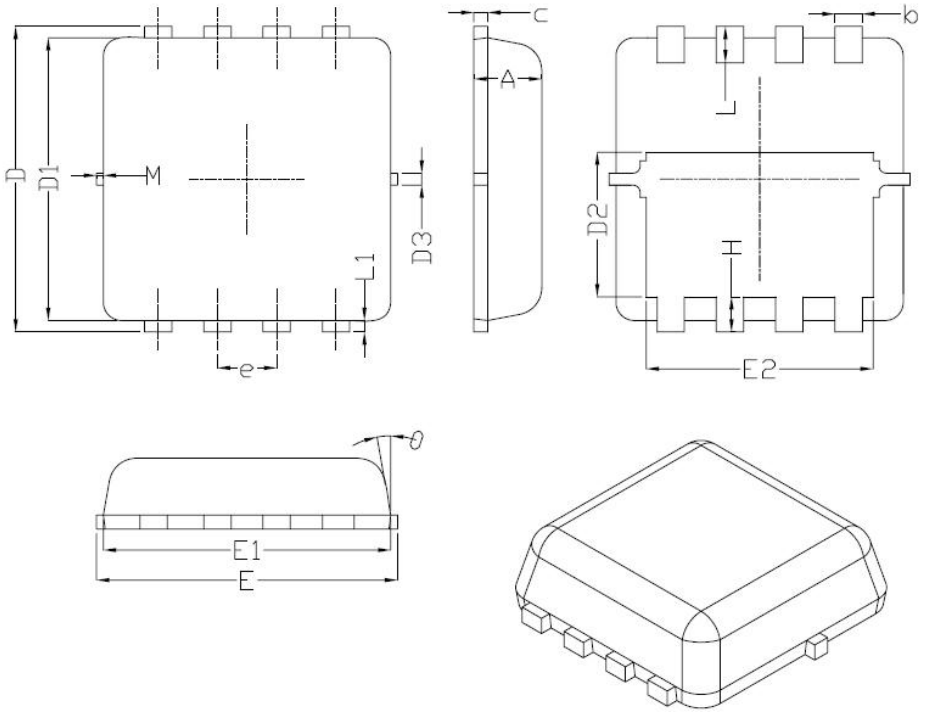


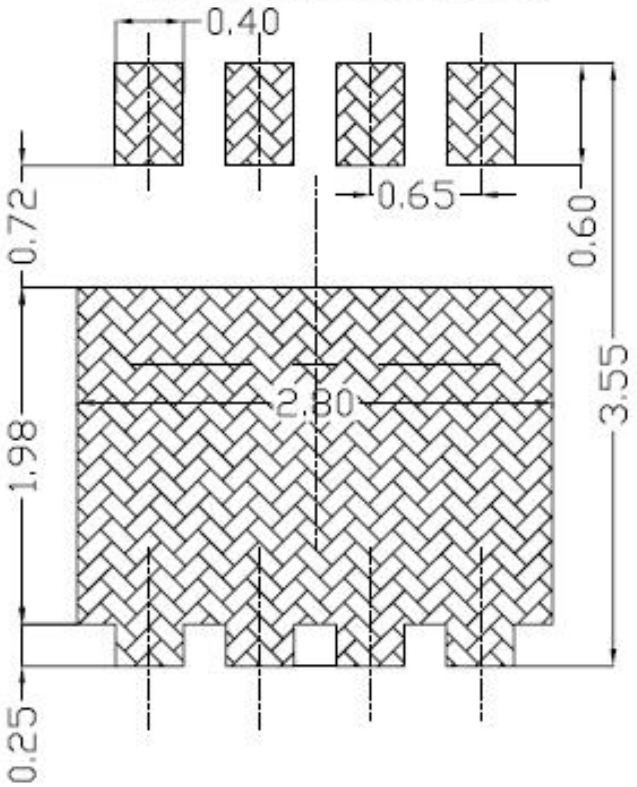

**Figure 11 Normalized Maximum Transient Thermal Impedance**

## DFN3.3X3.3-8L Package Information




| Symbol | Dimensions In Millimeters | | |
|---|---|---|---|
| | Min. | Nom. | Max. |
| A | 0.70 | 0.75 | 0.80 |
| b | 0.25 | 0.30 | 0.35 |
| c | 0.10 | 0.15 | 0.25 |
| D | 3.25 | 3.35 | 3.45 |
| D1 | 3.00 | 3.10 | 3.20 |
| D2 | 1.48 | 1.58 | 1.68 |
| D3 | - | 0.13 | - |
| E | 3.20 | 3.30 | 3.40 |
| E1 | 3.00 | 3.15 | 3.20 |
| E2 | 2.39 | 2.49 | 2.59 |
| e | 0.65BSC | | |
| H | 0.30 | 0.39 | 0.50 |
| L | 0.30 | 0.40 | 0.50 |
| L1 | - | 0.13 | - |
| M | * | * | 0.15 |
| θ | | 10° | 12° |

Land Pattern
(Only for Reference)



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